74CB3Q3253

Dual 1-of-4 FET multiplexer/demultiplexer with charge pump Rev. 2 — 28 June 2021 Product data sheet

1. General description

The 74CB3Q3253 is a dual high-bandwidth single-pole, quad-throw FET bus switch. Each switch features a select input (Sn) and an output enable input ($\overline{\text{nOE}}$). The switch is disabled when the $\overline{\text{nOE}}$ input is HIGH. An internal charge-pump increases the gate voltage of the NMOS pass transistor. The result is improved R_{ON} and R_{ON(flat)} performance and the ability to switch 5 V signals when V_{CC} = 3.3 V.

2. Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- Overvoltage switching on switch ports:
 - 0 V to 5 V switching with V_{CC} = 2.5 V
 - 0 V to 5 V switching with V_{CC} = 3.3 V
- Switch voltage accepts signals up to 5.5 V
- 4 Ω (typical) ON resistance
- 3.5 pF (typical) OFF-state capacitance
- High bandwidth 0.5 GHz (maximum)
- Low input/output capacitance minimizes loading and signal distortion
- Fast switching frequency f_{max} = 20 MHz (maximum)
- Low power consumption I_{CC} = 0.4 mA (typical)
- Control inputs can be driven by TTL or 5 V/3.3 V CMOS outputs
- I_{OFF} supports partial power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78E Class II Level A
- ESD protection:
 - HBM ANSI/ESDA/JEDEC JS-001-2012 Class 2 exceeds 2 kV
 - CDM JESD22-C101F exceeds 1000 V
- Specified from -40 °C to +85 °C

3. Applications

- Communication infrastructure
- Bus isolation
- Memory interleaving
- · Sensor multiplexing



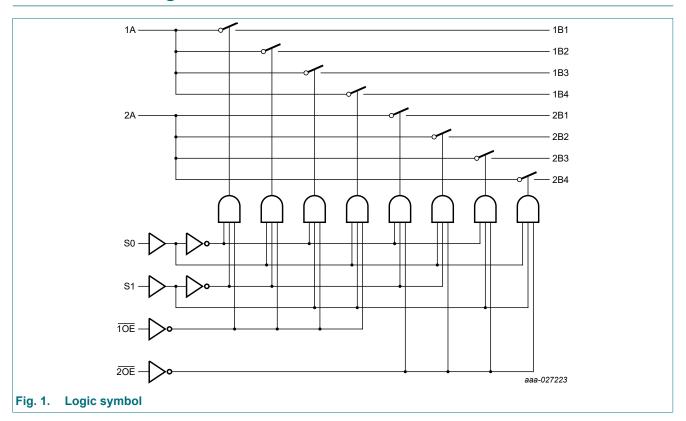
Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

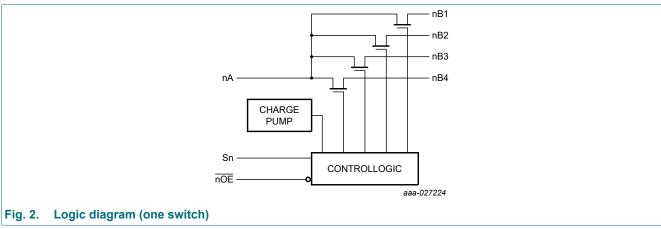
4. Ordering information

Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74CB3Q3253PW	-40 °C to +85 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					
74CB3Q3253BQ	-40 °C to +85 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm	SOT763-1					

5. Functional diagram

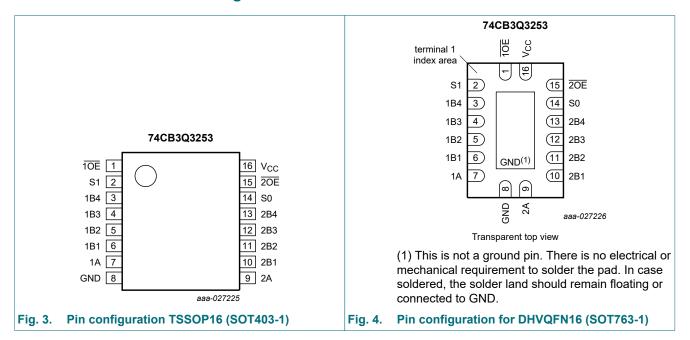




Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description		
10E	1	output enable input (active-LOW)		
S1	2	select input		
1B4	3	independent input or output		
1B3	4	independent input or output		
1B2	5	independent input or output		
1B1	6	independent input or output		
1A	7	common output or input		
GND	8	ground (0 V)		
2A	9	common output or input		
2B1	10	independent input or output		
2B2	11	independent input or output		
2B3	12	independent input or output		
2B4	13	independent input or output		
S0	14	select input		
20E	15	output enable input (active-LOW)		
Vcc	16	supply voltage		

Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

7. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Input			Channel on
S1	S0	nOE	
L	L	L	nA = nB1
L	Н	L	nA = nB2
Н	L	L	nA = nB3
Н	Н	L	nA = nB4
X	X	Н	Z (switch off)

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	Sn, nOE input [1]	-0.5	+7.0	V
V_{SW}	switch voltage	[2]	-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	-50	-	mA
I _{SK}	switch clamping current	V _I < -0.5 V	-50	-	mA
I _{SW}	switch current		-	±120	mA
I_{CC}	supply current		-	+100	mA
I_{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T_{amb} = -40 °C to +85 °C [3]	-	500	mW

^[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		2.3	3.6	V
VI	input voltage	Sn, nOE input	0	5.5	V
V_{SW}	switch voltage		0	5.5	V
T _{amb}	ambient temperature		-40	+85	°C
Δt/ΔV	input transition rise and fall rate	Sn, nOE input			
		V _{CC} = 2.3 V to 2.7 V	0	20	ns/V
		V _{CC} = 2.7 V to 3.6 V	0	10	ns/V

^[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

^[3] For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C. For SOT763-1 (DHVQFN16) package: P_{tot} derates linearly with 11.2 mW/K above 106 °C.

Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

10. Static characteristics

Table 6. Static characteristics

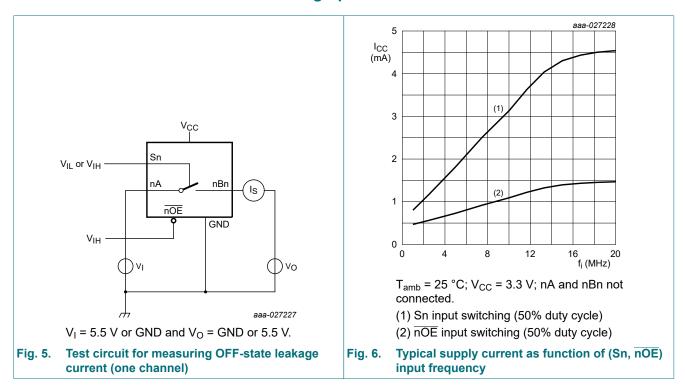
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	T,	_{amb} = 25	°C	T _{amb} =-40 °	C to +85 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V _{IH}	HIGH-level	V _{CC} = 2.3 V to 2.7 V	-	-	-	1.7	-	V
	input voltage	V _{CC} = 2.7 V to 3.6 V	-	-	-	2	-	V
V _{IL}	LOW-level	V _{CC} = 2.3 V to 2.7 V	-	-	-	-	0.7	V
	input voltage	V _{CC} = 2.7 V to 3.6 V	-	-	-	-	0.8	V
V _{IK}	input clamping voltage	nA; nBn; V _{CC} = 3.6 V; I _I = -18 mA	-	-	-	-	-1.8	V
I _I	input leakage current	Sn, nOE ; V _{CC} = 3.6 V; V _I = GND to 5.5 V	-	-	-	-	±1	μΑ
I _{OFF}	power-off leakage current	per pin; $V_{CC} = 0 \text{ V}$; V_{SW} or $V_I = 0 \text{ V}$ to 5.5 V	-	-	-	-	±1	μΑ
I _{S(OFF)}	OFF-state leakage current	nA; nBn; V _{CC} = 3.6 V; see <u>Fig. 5</u>	-	-	-	-	±1	μΑ
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{SW} = GND or V_{CC} ; V_{CC} = 3.6 V	-	0.4	-	-	0.6	mA
ΔI _{CC}	additional supply current	Sn, $\overline{\text{nOE}}$; V _{CC} = 3.6 V; one input at 3 V, other inputs at GND or V _{CC}	-	-	-	-	30	μΑ
C _I	input capacitance	V _{CC} = 3.3 V; V _{SW} = GND or V _{CC} ; V _I = 0 V, 3.3 V, 5.5 V						
		Sn, nOE	-	2.5	-	-	3.5	pF
C _{S(OFF)}	OFF-state	V _{CC} = 3.3 V; V _{SW} = 0 V, 3.3 V, 5.5 V						
	capacitance	nA	-	8	-	-	11	pF
		nBn		3.5	-	-	4.5	pF
C _{S(ON)}	ON-state	V _{CC} = 3.3 V; V _{SW} = 0 V, 3.3 V, 5.5 V						
	capacitance	nA, nBn	-	13	-	-	17	pF

^[1] Typical values are measured at V_{CC} = 3.3 V unless otherwise specified.

Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

10.1. Test circuit and graph



Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

10.2. ON resistance

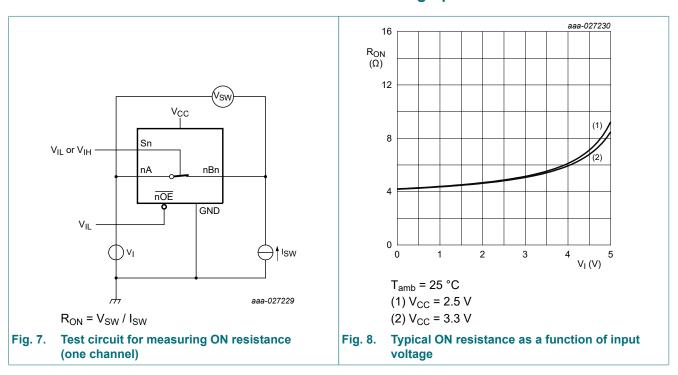
Table 7. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7.

Symbol	Parameter	Conditions	Т	amb = 25 °	С	T _{amb} = -40 °	Unit	
			Min	Тур	Max	Min	Max	
R _{ON}	ON resistance	V _{CC} = 2.3 V; see <u>Fig. 8</u>						
		$V_I = 0 \text{ V}; I_{SW} = 30 \text{ mA}$ [1]	-	4	-	-	10	Ω
		V _I = 1.7 V; I _{SW} = -15 mA [1]	-	4.5	-	-	11	Ω
		V _{CC} = 3.0 V; see <u>Fig. 8</u>						
		$V_I = 0 \text{ V}; I_{SW} = 30 \text{ mA}$ [2]	-	4	-	-	8	Ω
		V _I = 2.4 V; I _{SW} = -15 mA [2]	-	4.8	-	-	10	Ω

- [1] Typical values are measured at V_{CC} = 2.5 V.
- [2] Typical values are measured at V_{CC} = 3.3 V.

10.3. ON resistance test circuit and graph



Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

11. Dynamic characteristics

Table 8. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 11.

Symbol	Parameter	Conditions	T _{amb} = -40 °	°C to +85 °C	Unit
			Min	Max	
t _{pd}	propagation	nA to nBn or nBn to nA; see Fig. 9 [1] [2]			
	delay	V _{CC} = 2.3 V to 2.7 V	-	0.12	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.2	ns
		Sn to nA; see Fig. 9 [1]			
		V _{CC} = 2.3 V to 2.7 V	1.5	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	5.9	ns
t _{en}	enable time	nOE to nA, nBn; see Fig. 10 [1]			
		V _{CC} = 2.3 V to 2.7 V	1.5	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	5.9	ns
		Sn to nBn; see Fig. 10 [1]			
		V _{CC} = 2.3 V to 2.7 V	1.5	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	5.9	ns
t _{dis}	disable time	nOE to nA, nBn; see Fig. 10 [1]			
		V _{CC} = 2.3 V to 2.7 V	1.0	6.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	6.1	ns
		Sn to nBn; see Fig. 10 [1]			
		V _{CC} = 2.3 V to 2.7 V	1.0	6.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	6.1	ns
f _{max}	maximum	Sn, $\overline{\text{nOE}}$; $V_{\text{O}} > V_{\text{CC}}$; $V_{\text{I}} = 5 \text{ V}$; $R_{\text{L}} \ge 1 \text{ M}\Omega$; $C_{\text{L}} = 0 \text{ pF}$			
	frequency	V _{CC} = 2.3 V to 2.7 V	-	10	MHz
		V _{CC} = 3.0 V to 3.6 V	-	20	MHz

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

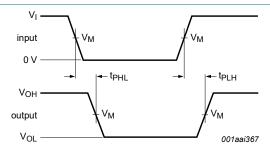
 t_{en} is the same as t_{PZL} and $t_{\text{PZH}}.$

 t_{dis} is the same as t_{PLZ} and $t_{\text{PHZ}}.$

^[2] The propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

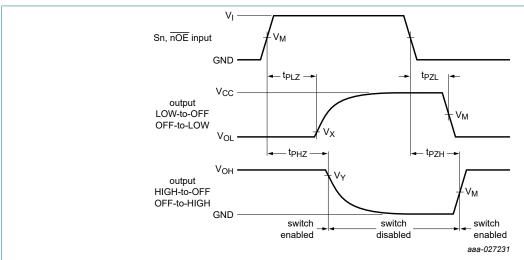
11.1. Waveforms and test circuit



Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 9. The data input (nA or nBn) to output (nBn or nA) propagation delays



Measurement points are given in Table 9.

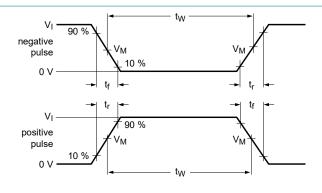
Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

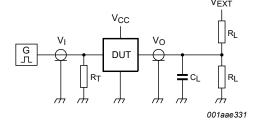
Fig. 10. Enable and disable times

Table 9. Measurement points

Supply voltage	Input	Output	Output					
V _{CC}	V _M	V _M	V _X	V _Y				
2.3 V to 2.7 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V				
3.0 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V				

Dual 1-of-4 FET multiplexer/demultiplexer with charge pump





Test data is given in Table 10.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig. 11. Test circuit for measuring switching times

Table 10. Test data

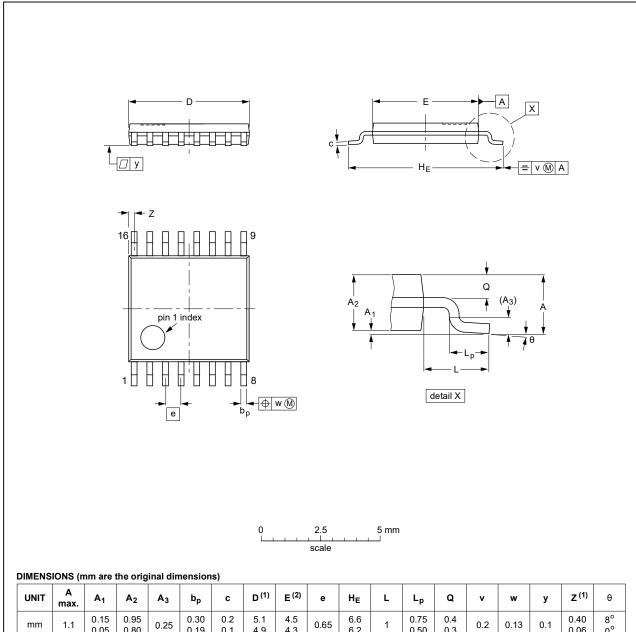
Supply voltage	Input		Load		V _{EXT}			
V _{CC}	VI	t _r , t _f	CL	R_L	t _{PLH} , t _{PHL}	t _{PLZ} , t _{PZL}	t _{PZH} , t _{PHZ}	
2.3 V to 2.7 V	V_{CC}	≤ 2.5 ns	30 pF	500 Ω	open	2 × V _{CC}	GND	
3.0 V to 3.6 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	2 × V _{CC}	GND	

Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

12. Package outline

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT403-1		MO-153			99-12-27 03-02-18	

Fig. 12. Package outline SOT403-1 (TSSOP16)

Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

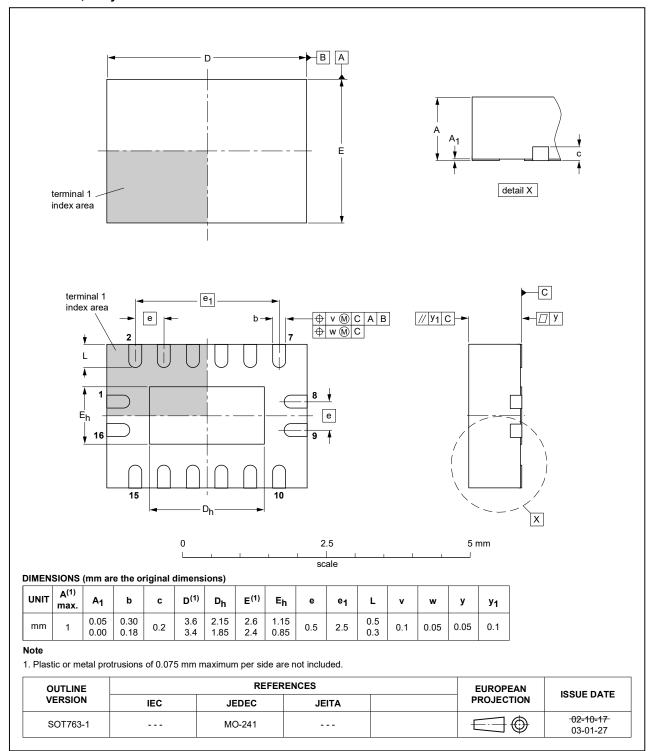


Fig. 13. Package outline SOT763-1 (DHVQFN16)

Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
FET	Field-Effect Transistor
НВМ	Human Body Model
NMOS	N-channel Metal-Oxide Semiconductor

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74CB3Q3253 v.2	20210628	Product data sheet	-	74CB3Q3253 v.1	
Modifications:	 Fig. 1: Logic symbol corrected. Section 8: Derating values for P_{tot} total power dissipation updated. 				
74CB3Q3253 v.1	20170814	Product data sheet	-	-	

13 / 15

Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Ordering information	2
5. Functional diagram	2
6. Pinning information	3
6.1. Pinning	
6.2. Pin description	3
7. Functional description	
8. Limiting values	
Recommended operating conditions	
10. Static characteristics	
10.1. Test circuit and graph	6
10.2. ON resistance	7
10.3. ON resistance test circuit and graph	7
11. Dynamic characteristics	8
11.1. Waveforms and test circuit	9
12. Package outline	11
13. Abbreviations	
14. Revision history	
15. Legal information	

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15 / 15

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